

Six Output Differential Buffer for PCIe Gen3

9DB633

Recommended Application:

6 output PCIe Gen3 zero-delay/fanout buffer

General Description:

The 9DB633 zero-delay buffer supports PCIe Gen3 requirements, while being backwards compatible to PCIe Gen2 and Gen1. The 9DB633 is driven by a differential SRC output pair from an IDT 932S421 or 932SQ420 or equivalent main clock generator. It attenuates jitter on the input clock and has a selectable PLL bandwidth to maximize performance in systems with or without Spread-Spectrum clocking. An SMBus interface allows control of the PLL bandwidth and bypass options, while 2 clock request (OE#) pins make the 9DB633 suitable for Express Card applications.

Key Specifications:

- Cycle-to-cycle jitter < 50 ps
- Output-to-output skew < 50 ps
- PCIe Gen3 phase jitter < 1.0ps RMS

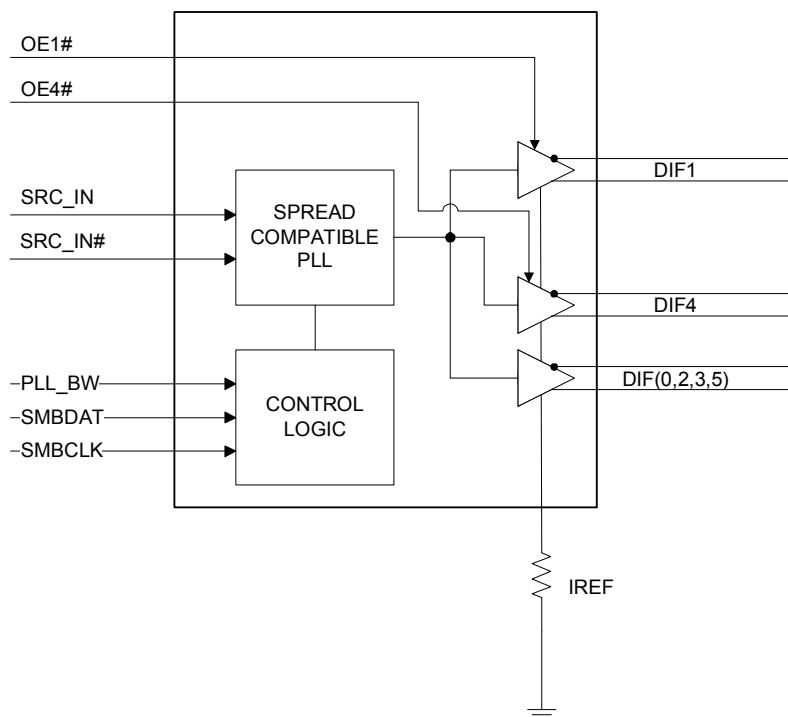
Features/Benefits:

- OE# pins/Suitable for Express Card applications
- PLL or bypass mode/PLL can dejitter incoming clock
- Selectable PLL bandwidth/minimizes jitter peaking in downstream PLL's
- Spread Spectrum Compatible/tracks spreading input clock for low EMI
- SMBus Interface/unused outputs can be disabled

Output Features:

- 6 - 0.7V current mode differential HCSL output pairs

Block Diagram



Pin Configuration

PLL_BW	1	9DB633	28	VDDA
SRC_IN	2		27	GNDA
SRC_IN#	3		26	IREF
vOE1#	4		25	vOE4#
DIF_0	5		24	DIF_5
DIF_0#	6		23	DIF_5#
VDD	7		22	VDD
GND	8		21	GND
DIF_1	9		20	DIF_4
DIF_1#	10		19	DIF_4#
DIF_2	11		18	DIF_3
DIF_2#	12		17	DIF_3#
VDD	13		16	VDD
SMBDAT	14		15	SMBCLK

Note: Pins preceded by 'v' have internal 120K ohm pull down resistors

Power Distribution Table

Pin Number		Description
VDD	GND	
7, 13, 16, 22	8, 21	Differential Outputs
13	8	SMBus
N/A	27	IREF
28	27	Analog VDD & GND for PLL core

Pin Description

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
1	PLL_BW	IN	3.3V input for selecting PLL Band Width 0 = low, 1= high
2	SRC_IN	IN	0.7 V Differential SRC TRUE input
3	SRC_IN#	IN	0.7 V Differential SRC COMPLEMENTARY input
4	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
5	DIF_0	OUT	0.7V differential true clock output
6	DIF_0#	OUT	0.7V differential Complementary clock output
7	VDD	PWR	Power supply, nominal 3.3V
8	GND	IN	Ground pin.
9	DIF_1	OUT	0.7V differential true clock output
10	DIF_1#	OUT	0.7V differential Complementary clock output
11	DIF_2	OUT	0.7V differential true clock output
12	DIF_2#	OUT	0.7V differential Complementary clock output
13	VDD	PWR	Power supply, nominal 3.3V
14	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
15	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
16	VDD	PWR	Power supply, nominal 3.3V
17	DIF_3#	OUT	0.7V differential Complementary clock output
18	DIF_3	OUT	0.7V differential true clock output
19	DIF_4#	OUT	0.7V differential Complementary clock output
20	DIF_4	OUT	0.7V differential true clock output
21	GND	PWR	Ground pin.
22	VDD	PWR	Power supply, nominal 3.3V
23	DIF_5#	OUT	0.7V differential Complementary clock output
24	DIF_5	OUT	0.7V differential true clock output
25	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
26	IREF	OUT	This pin establishes the reference for the differential current-mode output pairs. It requires a fixed precision resistor to ground. 475ohm is the standard value for 100ohm differential impedance. Other impedances require different values. See data sheet.
27	GNDA	PWR	Ground pin for the PLL core.
28	VDDA	PWR	3.3V power for the PLL core.

Note:

Pins preceeded by ' v ' have internal 120K ohm pull down resistors

Electrical Characteristics - Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
3.3V Core Supply Voltage	VDDA				4.6	V	1,2
3.3V Logic Supply Voltage	VDD				4.6	V	1,2
Input Low Voltage	V _{IL}		GND-0.5			V	1
Input High Voltage	V _{IH}	Except for SMBus interface			V _{DD} +0.5V	V	1
Input High Voltage	V _{IHSMB}	SMBus clock and data pins			5.5V	V	1
Storage Temperature	T _s		-65		150	°C	1
Junction Temperature	T _j				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

²Operation under these conditions is neither implied nor guaranteed.

Electrical Characteristics - Input/Supply/Common Parameters

TA = T_{COM} or T_{IND}; Supply Voltage VDD = 3.3 V +/-5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating Temperature	T _{COM}	Commercial range	0		70	°C	1
	T _{IND}	Industrial range	-40		85	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V _{DD} + 0.3	V	1
Input Low Voltage	V _{IL}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	V	1
Input Current	I _{IN}	Single-ended inputs, V _{IN} = GND, V _{IN} = VDD	-5		5	uA	1
	I _{INP}	Single-ended inputs V _{IN} = 0 V; Inputs with internal pull-up resistors V _{IN} = VDD; Inputs with internal pull-down resistors	-200		200	uA	1
Input Frequency	F _{ibyp}	V _{DD} = 3.3 V, Bypass mode	10		110	MHz	2
	F _{ipll}	V _{DD} = 3.3 V, 100MHz PLL mode	33	100.00	110	MHz	2
Pin Inductance	L _{pin}				7	nH	1
Capacitance	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T _{STAB}	From V _{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1.8	ms	1,2
Input SS Modulation Frequency	f _{MODIN}	Allowable Frequency (Triangular Modulation)	30		33	kHz	1
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	1		3	cycles	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of control inputs			5	ns	1,2
Trise	t _R	Rise time of control inputs			5	ns	1,2
SMBus Input Low Voltage	V _{ILSMB}				0.8	V	1
SMBus Input High Voltage	V _{IHSMB}		2.1		V _{DDSMB}	V	1
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4	V	1
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	1
Nominal Bus Voltage	V _{DDSMB}	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t _{RSMB}	(Max V _{IL} - 0.15) to (Min V _{IH} + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min V _{IH} + 0.15) to (Max V _{IL} - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			100	kHz	1,5

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴DIF_IN input

⁵The differential input clock must be running for the SMBus to be active

Electrical Characteristics - DIF_IN Clock Input Parameters

$T_{AMB}=T_{COM}$ or T_{IND} unless otherwise indicated, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V_{CROSS}	Cross Over Voltage	150	375	900	mV	1
Input Swing - DIF_IN	V_{SWING}	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	1		8	V/ns	1,2
Input Leakage Current	I_{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d_{in}	Measurement from differential waveform	45		55	%	1
Input Jitter - Cycle to Cycle	J_{DIFn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics - DIF 0.7V Current Mode Differential Outputs

$T_A = T_{COM}$ or T_{IND} ; Supply Voltage $V_{DD} = 3.3\text{ V} \pm 5\%$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on	0.6	2.5	4	V/ns	1, 2, 3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		9.5	20	%	1, 2, 4
Voltage High	V_{High}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope averaging on)	660	740	850	mV	1
Voltage Low	V_{Low}		-150	8	150		1
Max Voltage	V_{max}	Measurement on single ended signal using absolute value. (Scope averaging off)		760	1150	mV	1
Min Voltage	V_{min}		-300	-3			1
Vswing	V_{swing}	Scope averaging off	300	1506		mV	1, 2
Crossing Voltage (abs)	V_{cross_abs}	Scope averaging off	250	378	550	mV	1, 5
Crossing Voltage (var)	ΔV_{cross}	Scope averaging off		54	140	mV	1, 6

¹ Guaranteed by design and characterization, not 100% tested in production. $I_{REF} = V_{DD}/(3 \times R_R)$. For $R_R = 475\Omega$ (1%), $I_{REF} = 2.32\text{mA}$. $I_{OH} = 6 \times I_{REF}$ and $V_{OH} = 0.7\text{ V}$ @ $Z_O = 50\Omega$ (100 Ω differential impedance).

² Measured from differential waveform

³ Slew rate is measured through the V_{swing} voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ V_{cross} is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all V_{cross} measurements in any particular system. Note that this is a subset of $V_{cross_min/max}$ (V_{cross} absolute) allowed. The intent is to limit V_{cross} induced modulation by setting V_{cross_delta} to be smaller than V_{cross} absolute.

Electrical Characteristics - Current Consumption

$T_A = T_{COM}$ or T_{IND} ; Supply Voltage $V_{DD} = 3.3\text{ V} \pm 5\%$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	$I_{DD3.3OP}$	All outputs active @100MHz, $C_L = \text{Full load}$;		134	150	mA	1
Powerdown Current	$I_{DD3.3PD}$	All diff pairs driven			N/A	mA	1
	$I_{DD3.3PDZ}$	All differential pairs tri-stated			N/A	mA	1

¹ Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics - Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{COM} or T_{IND}; Supply Voltage VDD = 3.3 V +/-5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
PLL Bandwidth	BW	-3dB point in High BW Mode	2	2.3	4	MHz	1
		-3dB point in Low BW Mode	0.4	0.5	1	MHz	1
PLL Jitter Peaking	t _{JPEAK}	Peak Pass band Gain		1	2	dB	1
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	48	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode @100MHz	-2	1	2	%	1,4
Skew, Input to Output	t _{pdBYP}	Bypass Mode, V _T = 50%	2500	3660	4500	ps	1
	t _{pdPLL}	Hi BW PLL Mode V _T = 50%	-250	0	250	ps	1
Skew, Output to Output	t _{sk3}	V _T = 50%		15	50	ps	1
Jitter, Cycle to cycle	t _{jcy-cyc}	PLL mode		40	50	ps	1,3
		Additive Jitter in Bypass Mode		10	50	ps	1,3

¹Guaranteed by design and characterization, not 100% tested in production.

²I_{REF} = V_{DD}/(3xR_R). For R_R = 475Ω (1%), I_{REF} = 2.32mA. I_{OH} = 6 x I_{REF} and V_{OH} = 0.7V @ Z_O=50Ω.

³Measured from differential waveform

⁴Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

Electrical Characteristics - PCIe Phase Jitter Parameters

TA = T_{COM} or T_{IND}; Supply Voltage VDD = 3.3 V +/-5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Phase Jitter, PLL Mode	t _{jphPCIeG1}	PCIe Gen 1		32	86	ps (p-p)	1,2,3
	t _{jphPCIeG2}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.1	3	ps (rms)	1,2
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.3	3.1	ps (rms)	1,2
	t _{jphPCIeG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.5	1	ps (rms)	1,2,4
Additive Phase Jitter, Bypass Mode	t _{jphPCIeG1}	PCIe Gen 1		2	5	ps (p-p)	1,2,3
	t _{jphPCIeG2}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.2	0.3	ps (rms)	1,2
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.8	1	ps (rms)	1,2
	t _{jphPCIeG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.1	0.2	ps (rms)	1,2,4

¹Applies to all outputs.

²See <http://www.pcisig.com> for complete specs

³Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴Subject to final ratification by PCI SIG.

SRC Reference Clock			
Common Recommendations for Differential Routing		Dimension or Value	Unit Figure
L1 length, route as non-coupled 50ohm trace		0.5 max	inch 1
L2 length, route as non-coupled 50ohm trace		0.2 max	inch 1
L3 length, route as non-coupled 50ohm trace		0.2 max	inch 1
Rs		33	ohm 1
Rt		49.9	ohm 1

Down Device Differential Routing			
L4 length, route as coupled microstrip 100ohm differential trace		2 min to 16 max	inch 1
L4 length, route as coupled stripline 100ohm differential trace		1.8 min to 14.4 max	inch 1

Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace		0.25 to 14 max	inch 2
L4 length, route as coupled stripline 100ohm differential trace		0.225 min to 12.6 max	inch 2

Figure 1: Down Device Routing

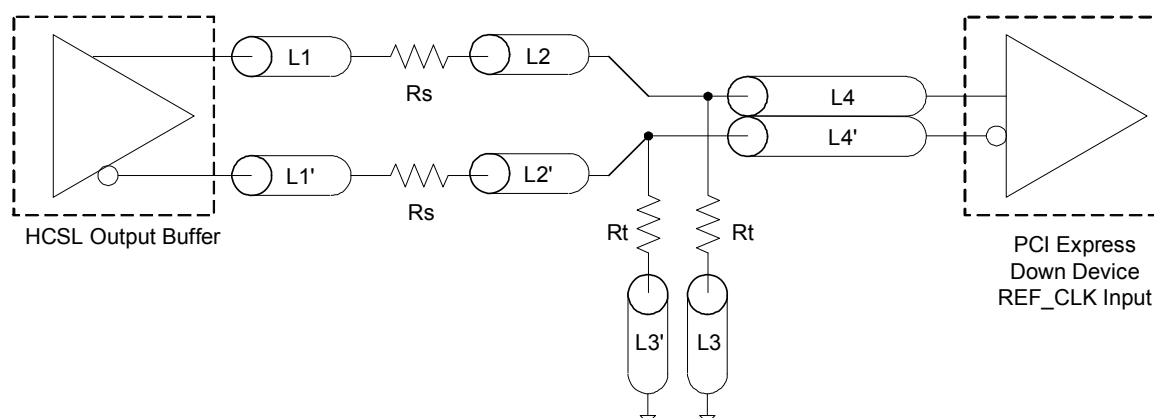
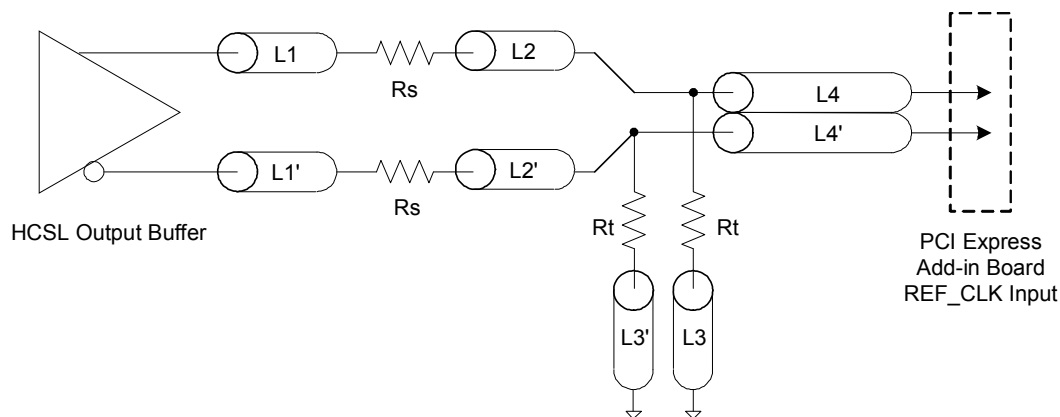


Figure 2: PCI Express Connector Routing

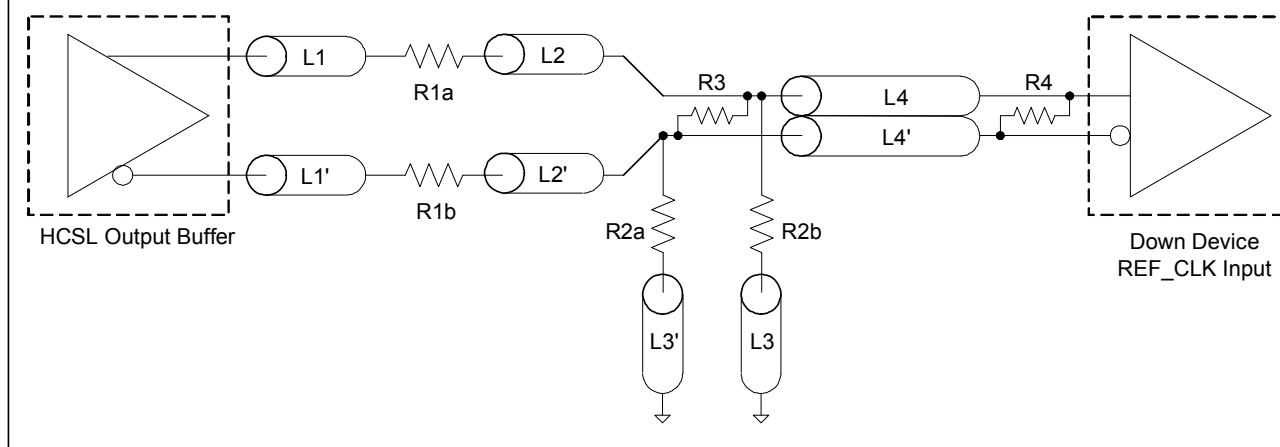


Alternative Termination for LVDS and other Common Differential Signals (figure 3)							
V _{diff}	V _{p-p}	V _{cm}	R1	R2	R3	R4	Note
0.45v	0.22v	1.08	33	150	100	100	
0.58	0.28	0.6	33	78.7	137	100	
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible
0.60	0.3	1.2	33	174	140	100	Standard LVDS

R1a = R1b = R1

R2a = R2b = R2

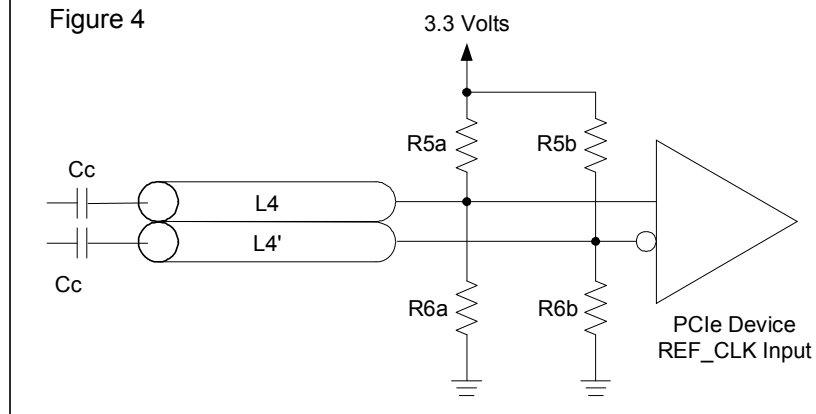
Figure 3



Cable Connected AC Coupled Application (figure 4)

Component	Value	Note
R5a, R5b	8.2K 5%	
R6a, R6b	1K 5%	
Cc	0.1 μ F	
V _{cm}	0.350 volts	

Figure 4



General SMBus serial interface information for the 9DB633

How to Write:

- Controller (host) sends a start bit.
- Controller (host) sends the write address $D4_{(H)}$
- ICS clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- ICS clock will **acknowledge**
- Controller (host) sends the data byte count = X
- ICS clock will **acknowledge**
- Controller (host) starts sending **Byte N through Byte N + X - 1**
(see Note 2)
- ICS clock will **acknowledge** each byte **one at a time**
- Controller (host) sends a Stop bit

How to Read:

- Controller (host) will send start bit.
- Controller (host) sends the write address $D4_{(H)}$
- ICS clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- ICS clock will **acknowledge**
- Controller (host) will send a separate start bit.
- Controller (host) sends the read address $D5_{(H)}$
- ICS clock will **acknowledge**
- ICS clock will send the data byte count = X
- ICS clock sends **Byte N + X - 1**
- ICS clock sends **Byte 0 through byte X (if $X_{(H)}$ was written to byte 8).**
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Index Block Write Operation		
Controller (Host)		ICS (Slave/Receiver)
T	starT bit	
Slave Address $D4_{(H)}$		
WR	WRite	
Beginning Byte = N		ACK
Data Byte Count = X		ACK
Beginning Byte N		ACK
<div style="display: flex; align-items: center;"> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> </div>		ACK
		○
		○
		○
Byte N + X - 1		ACK
P	stoP bit	

Index Block Read Operation		
Controller (Host)		ICS (Slave/Receiver)
T	starT bit	
Slave Address $D4_{(H)}$		
WR	WRite	
Beginning Byte = N		ACK
Data Byte Count = X		ACK
RT	Repeat starT	
Slave Address $D5_{(H)}$		
RD	ReaD	
ACK		ACK
ACK		
<div style="display: flex; align-items: center;"> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> </div>		Beginning Byte N
		○
		○
		○
Byte N + X - 1		
N	Not acknowledge	
P	stoP bit	

SMBusTable: Device Control Register, READ/WRITE ADDRESS (D5/D4)

Byte 0	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	SW_EN	Enables SMBus Control of bits (1:0)	RW	PLL controlled by SMBus registers	PLL controlled by device pins	1
Bit 6	-	RESERVED		RW	-	-	X
Bit 5	-	RESERVED		RW	-	-	X
Bit 4	-	RESERVED		RW	-	-	X
Bit 3	-	RESERVED		RW	-	-	X
Bit 2	-	RESERVED		RW	-	-	X
Bit 1	-	PLL BW #adjust	Selects PLL Bandwidth	RW	Low BW	High BW	1
Bit 0	-	PLL Enable	Bypasses PLL for board test	RW	PLL bypassed (fan out mode)	PLL enabled (ZDB mode)	1

SMBusTable: Output Enable Register

Byte 1	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	RESERVED		RW	-	-	X
Bit 6	-	RESERVED		RW	-	-	X
Bit 5	24,23	PCIEX5	Output Control	RW	Disable	Enable	1
Bit 4	-	RESERVED		RW	-	-	X
Bit 3	18,17	PCIEX3	Output Control	RW	Disable	Enable	1
Bit 2	11,12	PCIEX2	Output Control	RW	Disable	Enable	1
Bit 1	-	RESERVED		RW	-	-	X
Bit 0	5,6	PCIEX0	Output Control	RW	Disable	Enable	1

SMBusTable: Function Select Register

Byte 2	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	RESERVED		RW	-	-	X
Bit 6	-	RESERVED		RW	-	-	X
Bit 5	-	RESERVED		RW	-	-	X
Bit 4	-	RESERVED		RW	-	-	X
Bit 3	-	RESERVED		RW	-	-	X
Bit 2	-	RESERVED		RW	-	-	X
Bit 1	-	RESERVED		RW	-	-	X
Bit 0	-	RESERVED		RW	-	-	X

SMBusTable: Vendor & Revision ID Register

Byte 3	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	RID3	REVISION ID	R	-	-	0
Bit 6	-	RID2		R	-	-	0
Bit 5	-	RID1		R	-	-	0
Bit 4	-	RID0		R	-	-	1
Bit 3	-	VID3	VENDOR ID	R	-	-	0
Bit 2	-	VID2		R	-	-	0
Bit 1	-	VID1		R	-	-	0
Bit 0	-	VID0		R	-	-	1

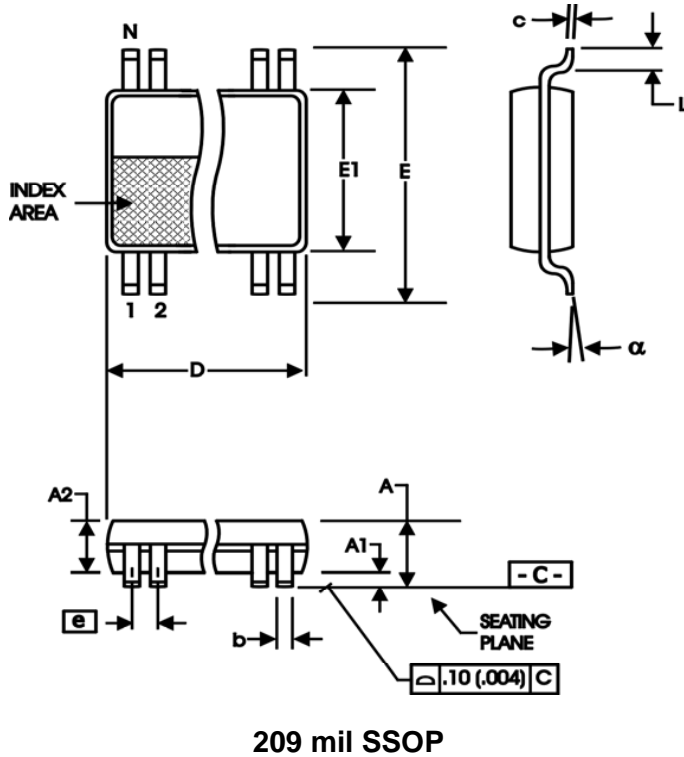
SMBusTable: DEVICE ID

Byte 4	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	Device ID = 06 Hex		R	-		0
Bit 6	-			R	-		0
Bit 5	-			R	-		0
Bit 4	-			R	-		0
Bit 3	-			R	-		0
Bit 2	-			R	-		1
Bit 1	-			R	-		1
Bit 0	-			R	-		0

SMBusTable: Byte Count Register

Byte 5	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	BC7	Writing to this register will configure how many bytes will be read back, default is 06 = 6 bytes.	RW	-	-	0
Bit 6	-	BC6		RW	-	-	0
Bit 5	-	BC5		RW	-	-	0
Bit 4	-	BC4		RW	-	-	0
Bit 3	-	BC3		RW	-	-	0
Bit 2	-	BC2		RW	-	-	1
Bit 1	-	BC1		RW	-	-	1
Bit 0	-	BC0		RW	-	-	0

28-pin SSOP Package Drawing and Dimensions



209 mil SSOP

SYMBOL	In Millimeters COMMON DIMENSIONS		In Inches COMMON DIMENSIONS	
	MIN	MAX	MIN	MAX
A	--	2.00	--	.079
A1	0.05	--	.002	--
A2	1.65	1.85	.065	.073
b	0.22	0.38	.009	.015
c	0.09	0.25	.0035	.010
D	SEE VARIATIONS		SEE VARIATIONS	
E	7.40	8.20	.291	.323
E1	5.00	5.60	.197	.220
e	0.65 BASIC		0.0256 BASIC	
L	0.55	0.95	.022	.037
N	SEE VARIATIONS		SEE VARIATIONS	
α	0°	8°	0°	8°

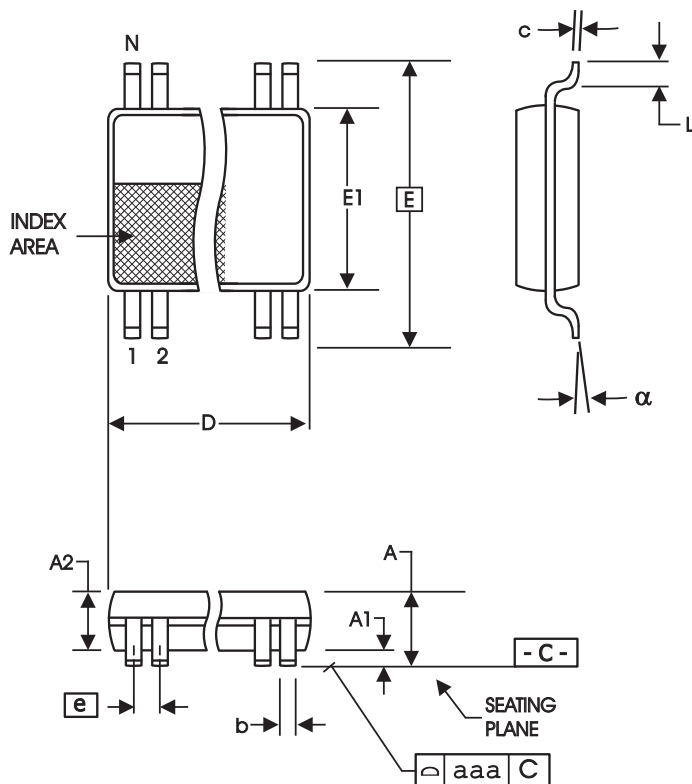
VARIATIONS

N	D mm.		D (inch)	
	MIN	MAX	MIN	MAX
28	9.90	10.50	.390	.413

Reference Doc.: JEDEC Publication 95, MO-150

10-0033

28-pin TSSOP Package Drawing and Dimensions



4.40 mm. Body, 0.65 mm. Pitch TSSOP

(173 mil) (25.6 mil)

SYMBOL	In Millimeters COMMON DIMENSIONS		In Inches COMMON DIMENSIONS	
	MIN	MAX	MIN	MAX
A	--	1.20	--	.047
A1	0.05	0.15	.002	.006
A2	0.80	1.05	.032	.041
b	0.19	0.30	.007	.012
c	0.09	0.20	.0035	.008
D	SEE VARIATIONS		SEE VARIATIONS	
E	6.40 BASIC		0.252 BASIC	
E1	4.30	4.50	.169	.177
e	0.65 BASIC		0.0256 BASIC	
L	0.45	0.75	.018	.030
N	SEE VARIATIONS		SEE VARIATIONS	
α	0°	8°	0°	8°
aaa	--	0.10	--	.004

VARIATIONS

N	D mm.		D (inch)	
	MIN	MAX	MIN	MAX
28	9.60	9.80	.378	.386

Reference Doc.: JEDEC Publication 95, MO-153

10-0035

Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DB633AFLF	Tubes	28-pin SSOP	0 to +70°C
9DB633AFLFT	Tape and Reel	28-pin SSOP	0 to +70°C
9DB633AFILF	Tubes	28-pin SSOP	-40 to +85°C
9DB633AFILFT	Tape and Reel	28-pin SSOP	-40 to +85°C
9DB633AGLF	Tubes	28-pin TSSOP	0 to +70°C
9DB633AGLFT	Tape and Reel	28-pin TSSOP	0 to +70°C
9DB633AGILF	Tubes	28-pin TSSOP	-40 to +85°C
9DB633AGILFT	Tape and Reel	28-pin TSSOP	-40 to +85°C

"LF" after the package code are the Pb-Free configuration and are RoHS compliant.

"A" is the device revision designator (will not correlate to the datasheet revision).

Revision History

Rev.	Originator	Issue Date	Description	Page #
A	RDW	6/30/2010	Released to final	
B	RDW	7/12/2010	Changed "PWD" to "Default" in SMBus Register descriptions	10,11
C	RDW	4/20/2011	Changed pull down indicator from '*' to 'v'.	
D	RDW	10/22/2013	Corrected typo for 28SSOP T&R orderable part number; "I" and "L" were swapped.	13
E	RDW	2/19/2014	Corrected typo for Read/Write address from D4/D5 to D5/D4 respectively	9,10
F	RDW	10/20/2016	Updated input clock electrical table to latest format. No change to form, fit or function of the device	5

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